

# Calculation of the Influence of the Crystalline Electric Field on the Spin-Disorder Resistivity of Rare-Earth Alloys and Comparison with Results on CeAl<sub>2</sub>†

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An expression is developed for the spin-disorder resistivity for metallic rare-earth systems; it takes into account the effect of the crystalline electric field. The expression, which is general, is made use of to treat the case of Ce<sup>3+</sup> in CeAl<sub>2</sub>; its resistivity-temperature behavior is adequately accounted for on the basis of a  $\Gamma_7$  doublet ground state.

## INTRODUCTION

The effect of localized magnetic moments on the electrical resistivity of rare-earth metals and alloys via the exchange scattering of conduction electrons is now well known.<sup>1</sup> When evaluated in the first Born approximation, this interaction gives rise, in the paramagnetic state, to a contribution which is usually termed as the spin-disorder resistivity.<sup>2</sup> In these calculations, if one ignores the crystal-field effects on the ground state of the rare-earth ion [i.e., effects associated with the total or partial lifting of  $(2J+1)$ -fold degeneracy], one obtains a temperature-independent term for the spin-disorder resistivity which is proportional to the quantity  $(g_J-1)^2 J(J+1)$  for the rare-earth ion. In interpreting the experimental resistivity data in the paramagnetic state of rare-earth alloys, such a temperature-independent expression for the spin-disorder resistivity is widely used<sup>3</sup>; indeed such a procedure is valid for temperatures sufficiently high compared to the crystal-field splitting that one may regard the different crystal-field states as being almost equally populated, as is shown below. However, recent heat-capacity measurements in this laboratory<sup>4</sup> have given direct evidence for the existence of sizable crystal-field splittings in a number of rare-earth intermetallic compounds. For example, the heat-capacity data on cubic CeAl<sub>2</sub> have revealed that the separation between the  $\Gamma_7$  doublet and the  $\Gamma_8$  quartet is of the order of 100°K.

In this paper, a method of evaluating the influence of the crystalline electric field is shown. Using this method the temperature variation of the spin-disorder resistivity is calculated for CeAl<sub>2</sub> and compared with the experimental measurements. The method, however, is of general applicability; it can readily be applied to other structures and to other rare-earth ions.

## SPIN-DISORDER RESISTIVITY IN ABSENCE OF CRYSTALLINE FIELD

As a prelude to our analysis, we shall briefly review the steps involved in the derivation of the spin-disorder resistivity in the rare earths.<sup>2</sup> We shall assume in the usual manner that the exchange interaction between a conduction electron of spin  $\mathbf{s}$  at  $\mathbf{r}$  and a rare-earth atom

of spin  $\mathbf{S}$  at  $\mathbf{R}$  can be written as

$$\mathcal{H} = -2G\delta(\mathbf{r}-\mathbf{R})\mathbf{s}\cdot\mathbf{S}, \quad (1)$$

where  $G$  is a quantity with the dimensions energy times volume. As a result of spin-orbit coupling, Eq. (1) can be rewritten in terms of the total angular momentum  $\mathbf{J}$  as

$$\begin{aligned} \mathcal{H} &= -2G(g-1)\delta(\mathbf{r}-\mathbf{R})\mathbf{s}\cdot\mathbf{J} \\ &= -2G(g-1)\delta(\mathbf{r}-\mathbf{R})[s_z J_z + \frac{1}{2}(s_+ J_- + s_- J_+)], \end{aligned} \quad (2)$$

where  $g$  is the Landé factor of the rare-earth ion.

In the absence of electric or magnetic fields, the  $(2J+1)$  eigenstates of the ground  $J$  multiplet are degenerate in the paramagnetic state and can be labeled by the eigenvalues  $(m_J)$  of  $J_z$ . A conduction electron in a state  $\mathbf{k}$  moving in the vicinity of a rare-earth atom is scattered by the potential (2) into a new state  $\mathbf{k}'$ . The scattering occurs without spin flip if the initial and final states are connected by the term  $s_z J_z$  in the Hamiltonian and with spin flip if they are connected by the terms  $s_{\pm} J_{\mp}$ .

The scattering probability for a particular process is, in the first Born approximation, proportional to the absolute square of the matrix element  $M_{ii'}(\mathbf{k}\rightarrow\mathbf{k}')$  connecting the initial ( $i$ ) and final ( $i'$ ) states of the system. The transport properties are then discussed in terms of the relaxation times  $\tau_{F\pm}$  for electrons with spin up and spin down, respectively, at the Fermi surface. The relaxation times are inversely proportional to the scattering probabilities and are given by<sup>5</sup>

$$\begin{aligned} \frac{1}{\tau_{F\pm}} &= \frac{mk_F}{\pi\hbar^3} \left( \sum_{i,i'} N_i |M_{ii'}(\mathbf{k}_{\pm}\rightarrow\mathbf{k}_{\pm}')|^2 \frac{2}{1+\exp(-E_{ii'}/k_B T)} \right. \\ &\quad \left. + \sum_{j,j'} N_j |M_{jj'}(\mathbf{k}_{\pm}\rightarrow\mathbf{k}_{\mp}')|^2 \frac{2}{1+\exp(-E_{jj'}/k_B T)} \right), \end{aligned} \quad (3)$$

where  $E_{ii'}$  and  $E_{jj'}$  are the energies gained by the electrons in the particular scattering processes.  $N_i$  and  $N_j$  are the numbers of scattering centers per unit volume producing the respective collision processes. The conductivities  $\sigma_{e\pm}$  are then related to  $\tau_{F\pm}$  through the well-known formula

$$\sigma_{e\pm} = (n_{\pm} e^2 / m) \tau_{F\pm}, \quad (4)$$

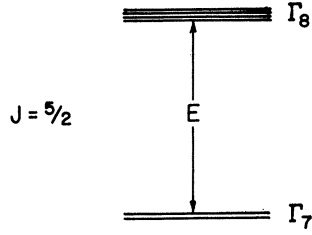


FIG. 1. Cubic crystal-field splitting of the ground state ( $J = \frac{5}{2}$ ) of  $\text{Ce}^{3+}$  ion into doublet ( $\Gamma_7$ ) and quartet ( $\Gamma_8$ ) levels. The sign of the crystal field establishes whether  $\Gamma_7$  or  $\Gamma_8$  is lower lying.

where  $n_{\pm}$  are the numbers of conduction electrons with spin up or spin down, respectively. In the absence of electric and magnetic fields, all the  $m_J$  substates of the rare-earth ion are equally probable, since they are degenerate, and all  $E_{ii'} = E_{jj'} = 0$ , since all collisions are elastic. The spin-disorder resistivity  $\rho_{s1}^0$  under these conditions becomes

$$\rho_{s1}^0 = (3\pi N m / 2\hbar e^2 E_F) G^2 (g-1)^2 J(J+1), \quad (5)$$

where  $N$  is the number of scattering centers per unit volume. From Eq. (5) it is seen that  $\rho_{s1}^0$  is independent of temperature. Here, as in the rest of this paper, the subscript  $s1$  denotes that the resistivity has been obtained correct to the first Born approximation.  $\rho_{s2}$  will represent the additional contribution when the resistivity is evaluated in the second Born approximation.

### SPIN-DISORDER RESISTIVITY IN PRESENCE OF CRYSTAL FIELD

When the effect of the crystal-field interaction is included, the above procedure has to be modified in the following manner. First, the eigenstates are no longer pure  $m_J$  states but are admixtures of them. The matrix elements  $M_{ii'}$  and  $M_{jj'}$  in Eq. (3) should now be taken between the crystal-field states. Second, the probability  $p_i$  of a rare-earth atom being in a certain crystal-field state  $i$  of energy  $E_i$  depends on the extent of the crystal-field splitting and on the temperature through the Boltzmann relation

$$p_i = \frac{N_i}{N} = \frac{\exp(-E_i/k_B T)}{\sum_j \exp(-E_j/k_B T)}. \quad (6)$$

Finally, some of the collisions will be inelastic, and the  $E_{ii'}$  and  $E_{jj'}$  in Eq. (3) will not all be zero.

With these modifications, and using Eqs. (3) and (4), the expression for the resistivity at a temperature  $T$  becomes

$$\rho_{s1}(T) = \frac{3\pi N m}{\hbar e^2 E_F} G^2 (g-1)^2 \times \sum_{m_s, m_s', i, i'} \langle m_s', i' | \mathbf{s} \cdot \mathbf{J} | m_s, i \rangle^2 p_{if_{ii'}}, \quad (7)$$

where  $m_s$  and  $m_s'$  are the spins of the conduction electron in the initial and final states and the matrix ele-

ments are between the simultaneous eigenstates for the local-moment-conduction-electron system. The  $f_{ii'}$  in Eq. (7) are given by

$$f_{ii'} = \frac{2}{1 + \exp(-E_{ii'}/k_B T)}. \quad (8)$$

### APPLICATION TO CERIUM IN CUBIC CRYSTAL FIELD; COMPARISON WITH EXPERIMENT

It is well known that a cubic crystal field splits the ground multiplet ( $J = \frac{5}{2}$ ) of the  $\text{Ce}^{3+}(f^1)$  ion into a  $\Gamma_7$  doublet and a  $\Gamma_8$  quartet (Fig. 1). These states are described by the following linear combinations of the pure  $m_J$  states<sup>6</sup>:

$$| \Gamma_7 \rangle = a | \pm \frac{5}{2} \rangle - b | \mp \frac{3}{2} \rangle,$$

$$| \Gamma_8 \rangle = b | \pm \frac{5}{2} \rangle + a | \mp \frac{3}{2} \rangle,$$

and

$$| \pm \frac{1}{2} \rangle,$$

where  $a = 0.4083$  and  $b = 0.9129$ . The matrix elements in Eq. (7) are taken between the above crystal-field eigenstates. In this particular case, Eq. (7) can then be written

$$\rho_{s1}(T) = (3\pi N m / \hbar e^2 E_F) G^2 (g-1)^2 \times [2a^2(3a^2-1)(p_1+p_2-p_1f_1-p_2f_2) + (9/4)p_1+11p_2+\frac{13}{2}(p_1f_1+p_2f_2)], \quad (9)$$

where  $p_1$  and  $p_2$  are the probabilities that a given state in the  $\Gamma_7$  and  $\Gamma_8$  manifolds, respectively, is occupied. If  $E$ , the separation between the two levels, is taken to be positive when the  $\Gamma_7$  doublet is lower and negative when the  $\Gamma_8$  quartet is lower, we have, with  $x = \exp(-E/k_B T)$ ,  $p_1 = (2+4x)^{-1}$  and  $p_2 = xp_1$ .  $f_1$  and  $f_2$

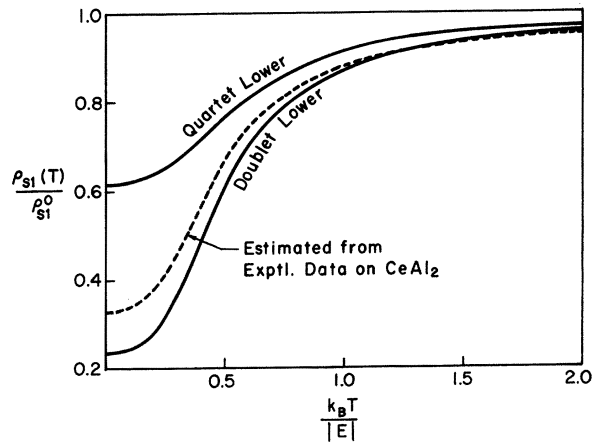


FIG. 2. Theoretical curves for the variation of spin-disorder resistivity of  $\text{CeAl}_2$  with temperature under the influence of a cubic crystal field for (a) doublet lower and (b) quartet lower are shown by the solid lines.  $\rho_{s1}(T)$  and  $\rho_{s1}^0$  are given by Eqs. (7) and (5). The dotted curve is the experimental curve estimated from data on  $\text{CeAl}_2$  (see Fig. 3).

in Eq. (9) are given by  $f_1 = 2(1+x^{-1})^{-1}$  and  $f_2 = 2(1+x)^{-1}$ .

It is easily seen from Eq. (9) that at temperatures high compared to  $|E|$ ; i.e., as  $x \rightarrow 1$ , the quantity inside the square brackets in Eq. (9) tends to the value  $35/8$ . Thus Eq. (9) in this limit becomes identical to the Eq. (5) for  $\rho_{s1}^0$  with  $J = \frac{5}{2}$ .

Expression (9) was evaluated for different temperatures with (a) doublet lying lower and (b) quartet lying lower. The variation of  $\rho_{s1}(T)/\rho_{s1}^0$  with  $k_B T/|E|$  is shown in Fig. 2. It is seen that  $\rho_{s1}(T)$  tends to a much lower value as  $T \rightarrow 0$  when the doublet is lower than when the quartet is lower.

The experimental  $\rho$ -versus- $T$  curve for  $\text{CeAl}_2$  was first obtained by van Daal and Buschow.<sup>7</sup> Measurements on this compound made in this laboratory were in satisfactory agreement with those of these authors. The measured resistivity (from which the residual resistivity of about  $20 \mu\Omega \text{ cm}$  has been subtracted) is plotted as a function of temperature between 6 and  $290^\circ\text{K}$  as the solid curve in Fig. 3. In other words, the solid curve in Fig. 3 is the sum of two contributions

$$\rho(T) = \rho_l(T) + \rho_s(T),$$

where  $\rho_l(T)$  is the lattice part and  $\rho_s(T)$  is the spin-disorder part. The second-order contribution to  $\rho_s$  is included, i.e.,  $\rho_s(T) = \rho_{s1}(T) + \rho_{s2}(T)$ .

$\text{CeAl}_2$  has the cubic Laves structure and the environment of the Ce atoms is also cubic so that our theory is applicable to this compound. The upturn in the  $\rho$ - $T$  curve below  $15^\circ\text{K}$  is now regarded as a Kondo anomaly.<sup>8</sup> The point of interest to us is the unusual broad "knee" in the  $\rho$ - $T$  curve at about  $70^\circ\text{K}$ . We ascribe this behavior to the influence of the crystal field on the spin-disorder resistivity. The only other contribution strongly dependent on temperature in this region is the lattice or phonon part,  $\rho_l(T)$ . The isomorphous but nonmagnetic compounds  $\text{LaAl}_2$ ,  $\text{YbAl}_2$ , and  $\text{YAl}_2$ , where the lattice contribution to resistivity might be expected to be similar to that of  $\text{CeAl}_2$ , do not show this behavior.<sup>7</sup>

The general shape of the  $\rho$ - $T$  curve in the temperature range (i.e., above  $20^\circ\text{K}$ ) of interest is satisfactorily accounted for by our analysis as may be seen by a comparison of Figs. 2 and 3. To make a quantitative comparison between theory and experiment, one would have to subtract the lattice contribution  $\rho_l(T)$  as well as the contribution  $\rho_{s2}(T)$  described earlier from the measured resistivity. It can be seen from Fig. 3 that at high temperatures ( $T > 100^\circ\text{K}$ ) the  $\rho$ - $T$  curve is linear with a slope of  $0.091 \mu\Omega \text{ cm } ^\circ\text{K}^{-1}$ , which may be compared with the value of about  $0.12 \mu\Omega \text{ cm } ^\circ\text{K}^{-1}$  observed in nonmagnetic  $\text{YbAl}_2$  and  $\text{YAl}_2$ . The temperature dependence of  $\rho$  in this region arises almost entirely from the variation of  $\rho_l(T)$  with  $T$ . An estimation of  $\rho_l(T)$  for  $\text{CeAl}_2$  was made by scaling the entire  $\rho_l(T)$ -versus- $T$  curve of  $\text{YbAl}_2$ <sup>7</sup> by a constant factor in such a way that the slope of the curve at high temperatures (above  $100^\circ\text{K}$ ) was equal to that of the

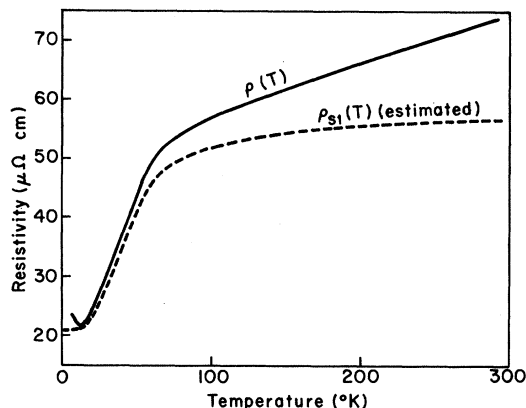


FIG. 3. Solid curve gives the measured resistivity of  $\text{CeAl}_2$  from which the residual resistivity has been subtracted. The dotted curve shows the estimated spin-disorder resistivity  $\rho_{s1}(T)$ .

experimental  $\rho(T)$ -versus- $T$  curve of  $\text{CeAl}_2$  shown in Fig. 3.  $\rho_{s2}(T)$  has also been estimated by noting that this term is solely responsible for the upturn in the  $\rho$ -versus- $T$  curve (the Kondo phenomenon) below about  $15^\circ\text{K}$  and that above this temperature its contribution is quite negligible. Subtracting these estimated values of  $\rho_l(T)$  and  $\rho_{s2}(T)$  from the measured resistivity, one obtains the estimated  $\rho_{s1}(T)$ -versus- $T$  curve, which is shown as the dotted line in Fig. 3 and also in Fig. 2, for a comparison with the theoretical curves. To plot the latter curve, the crystal-field separation in  $\text{CeAl}_2$  has been taken to be  $100^\circ\text{K}$  which is the value given by neutron-scattering measurements.<sup>9</sup> It is apparent from Fig. 2 that the curve of  $\rho_{s1}(T)$  versus  $T$  for  $\text{CeAl}_2$  estimated from the experimental data is in much better agreement with the theoretical curve when the  $\Gamma_7$  doublet is the lower-lying level than when the  $\Gamma_8$  quartet is the lower-lying level. From heat-capacity measurements in the temperature range  $0.5$ – $15^\circ\text{K}$ , Hill and da Silva<sup>10</sup> have also come to the conclusion that the  $\Gamma_7$  level is the lower-lying level.

## CONCLUSIONS

The influence of the crystalline electric field on the spin-disorder resistivity has been shown to be of importance at temperatures lower than the crystal-field splitting of the rare-earth ions in rare-earth alloys and intermetallic compounds. A method of quite general applicability has been put forward for the calculation of the spin-disorder resistivity as a function of temperature in the presence of a crystal field. The method has been illustrated by a calculation for  $\text{Ce}^{3+}$  ion in a cubic crystal field and is found to yield results in substantial agreement with the measured resistivity of  $\text{CeAl}_2$ .

The crystal field should also have interesting consequences on a calculation of the resistivity in the second Born approximation. This aspect is presently being investigated and will be reported later.

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<sup>1</sup> See, e.g., T. Kasuya, *Progr. Theoret. Phys. (Kyoto)* **16**, 58 (1956); **22**, 227 (1959); P. G. deGennes and J. Friedel, *J. Phys. Chem. Solids* **4**, 71 (1958); P. G. deGennes, *J. Phys. Radium* **23**, 510 (1962).

<sup>2</sup> See A. J. Dekker, *J. Appl. Phys.* **36**, 906 (1965), for a review of this problem.

<sup>3</sup> See, e.g., Ref. 7.

<sup>4</sup> W. E. Wallace, R. S. Craig, A. Thompson, C. Deenadas, M. Dixon, M. Aoyagi, and N. Marzouk, *The Rare-Earth Elements* (Centre National de la Recherche Scientifique, Paris, 1970), p. 427.

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<sup>7</sup> H. J. van Daal and K. H. J. Buschow, *Solid State Commun.* **7**, 217 (1969).

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<sup>9</sup> B. D. Rainford, D. Phil. thesis, Oxford, 1969 (unpublished), quoted in Ref. 10.

<sup>10</sup> R. W. Hill and J. M. Machado da Silva, *Phys. Letters* **30A**, 13 (1969).

## Generalization of Conditions due to Domb for Reducing the Number of Unknown Terms in the Ising Fugacity Expansion\*

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The derivation of low-temperature series for the Ising model is simplified by a high-temperature symmetry condition, a general proof of which does not exist in the open literature. The magnetic linked-cluster expansion provides an elementary and general proof.

### BACKGROUND

We present the proof in detail for the free energy  $F$  of the nearest-neighbor  $S = \frac{1}{2}$  Ising model. The straightforward generalization to  $S > \frac{1}{2}$ , longer-range interactions, and physical quantities other than  $F$  is indicated in conclusion. The Hamiltonian of the model is

$$-\beta\mathcal{H} = v \sum_{\langle ij \rangle} \sigma_i \sigma_j + h \sum_i \sigma_i, \quad (1)$$

where  $\sigma_i = 1 (-1)$  for spin up (down), the indices range over lattice sites, and the sum in the first term is over nearest-neighbor pairs. The free energy is given by  $-\beta F = \ln \text{Tr} e^{-\beta\mathcal{H}}$ .

At low temperatures (1) can usefully be rewritten in terms of operators measuring the deviation from complete alignment,  $n_i \equiv \frac{1}{2}(1 - \sigma_i)$ ,

$$-\beta\mathcal{H} = N(\frac{1}{2}qv + h) + 4v \sum_{\langle ij \rangle} n_i n_j - 2(h + qv) \sum_i n_i, \quad (2)$$

where  $q$  is the number of nearest neighbors. The low-temperature (high-field) series for  $F$  is<sup>1</sup> just the Yvon-Mayer expansion with chemical potential  $-2(h + qv)$ . The free energy can be written as

$$-\frac{\beta F}{N} = \frac{1}{2}qv + h + \sum_{n=1}^{\infty} \mu^n L_n(u), \quad (3)$$

where  $\mu = e^{-2h}$ ,  $u = e^{-4v}$ , and the  $L_n(u)$  are finite polynomials<sup>2</sup> in  $u$ ,

$$L_n(u) = u^{nq/2} \sum_{r=0}^{n(n-1)} [n, r] u^{-r}.$$

The coefficients  $[n, r]$  may be determined from the Mayer graphs. The quantity  $(1-u)$  is a high-temperature variable, so high-temperature series can be derived from (3),

$$-\frac{\beta F}{N} = \frac{1}{2}qv + h + \sum_{n=1}^{\infty} \sum_{r=0}^{\infty} (-1)^r \mu^n \times \frac{(1-u)^r}{r!} \frac{\partial^r L_n(u)}{\partial u^r} \Big|_{u=1}. \quad (4)$$

### SYMMETRY CONDITION AND ITS USE

It is easy to see from (1) that the free energy  $F$  has the symmetry  $F(v, h) = F(v, -h)$ . This symmetry, which is explicit in the high-temperature series, is lost at low temperatures, where series converge only for  $\mu \leq 1$ . The high-temperature symmetry condition is

$$-\frac{\beta F}{N} = \frac{1}{2}qv + h + \ln(1+\mu) + \sum_{r=1}^{\infty} (1-u)^r \frac{\varphi_r(\mu)}{(1+\mu)^{2r}}, \quad (5)$$

with the specification that

$$\varphi_r(\mu) \equiv \sum_{n=1}^{2r-1} \varphi_r^{(n)} \mu^n$$

is a finite polynomial having the symmetry  $\varphi_r(\mu) = \mu^{2r} \varphi_r(1/\mu)$ . Note that this incorporates invariance under  $h \leftrightarrow -h$ . Equation (5) was first conjectured by Domb<sup>3</sup> and has subsequently been proved for various cases.<sup>4</sup> To our knowledge there is no proof in the open literature which is applicable to close-packed lattices and spins greater than  $\frac{1}{2}$ .